

# TLV2432-Q1, TLV2432A-Q1, TLV2434-Q1, TLV2434A-Q1 Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT WIDE-INPUT-VOLTAGE OPERATIONAL AMPLIFIERS

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- Qualification in Accordance With AEC-Q100†
- Qualified for Automotive Applications
- Customer-Specific Configuration Control Can Be Supported Along With Major-Change Approval
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Output Swing Includes Both Supply Rails
- Extended Common-Mode Input Voltage Range . . . 0 V to 4.5 V (Min) with 5-V Single Supply
- No Phase Inversion
- Low Noise . . . 18 nV/√Hz Typ at f = 1 kHz
- Low Input Offset Voltage  
950 μV Max at T<sub>A</sub> = 25°C (TLV243xA)
- Low Input Bias Current . . . 1 pA Typ
- Very Low Supply Current . . . 125 μA Per Channel Max
- 600-Ω Output Drive
- Macromodel Included

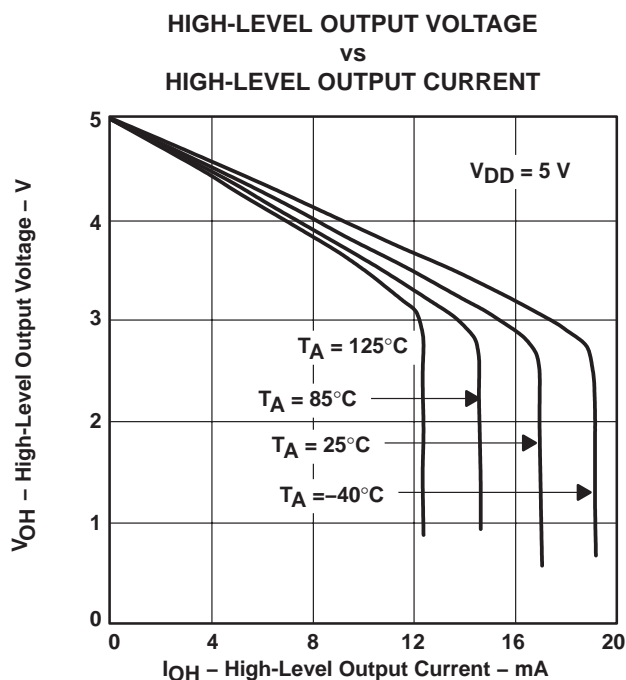
† Contact factory for details. Q100 qualification data available on request.

## description

The TLV243x and TLV243xA are low-voltage operational amplifier from Texas Instruments. The common-mode input voltage range for each device is extended over the typical CMOS amplifiers making them suitable for a wide range of applications. In addition, these devices do not phase invert when the common-mode input is driven to the supply rails. This satisfies most design requirements without paying a premium for rail-to-rail input performance. They also exhibit rail-to-rail output performance for increased dynamic range in single- or split-supply applications. This family is fully characterized at 3-V and 5-V supplies and is optimized for low-voltage operation. The TLV243x only requires 100 μA (typ) of supply current per channel, making it ideal for battery-powered applications. The TLV243x also has increased output drive over previous rail-to-rail operational amplifiers and can drive 600-Ω loads for telecom applications.

The other members in the TLV243x family are the high-power, TLV244x, and micro-power, TLV2422, versions.

The TLV243x, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels and low-voltage operation, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single- or split-supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLV243xA is available and has a maximum input offset voltage of 950 μV.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS  
INSTRUMENTS**

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# TLV2432-Q1, TLV2432A-Q1, TLV2434-Q1, TLV2434A-Q1

## Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT

### WIDE-INPUT-VOLTAGE OPERATIONAL AMPLIFIERS

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#### description (continued)

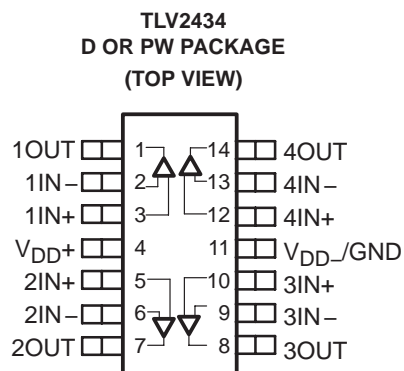
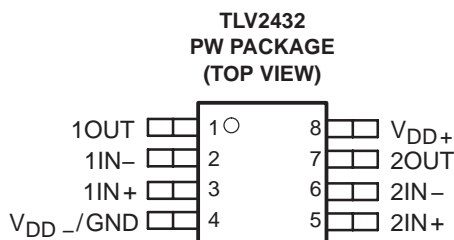
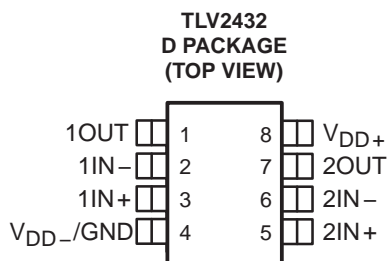
If the design requires single operational amplifiers, see the TI TLV2211/21/31. This is a family of rail-to-rail output operational amplifiers in the SOT-23 package. Their small size and low power consumption, make them ideal for high density, battery-powered equipment.

#### ORDERING INFORMATION†

TA	V <sub>IO</sub> max AT 25°C	PACKAGE		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	950 µV	SOIC (D)	Tape and reel	TLV2432AQDRQ1	2432AQ
		TSSOP (PW)	Tape and reel	TLV2432AQPWRQ1‡	
	2.5 mV	SOIC (D)	Tape and reel	TLV2432QDRQ1	2432Q1
		TSSOP (PW)	Tape and reel	TLV2432QPWRQ1‡	
-40°C to 125°C	950 µV	SOIC (D)	Tape and reel	TLV2434AQDRQ1‡	
		TSSOP (PW)	Tape and reel	TLV2434AQPWRQ1‡	
	2.5 mV	SOIC (D)	Tape and reel	TLV2434QDRQ1‡	
		TSSOP (PW)	Tape and reel	TLV2434QPWRQ1‡	

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

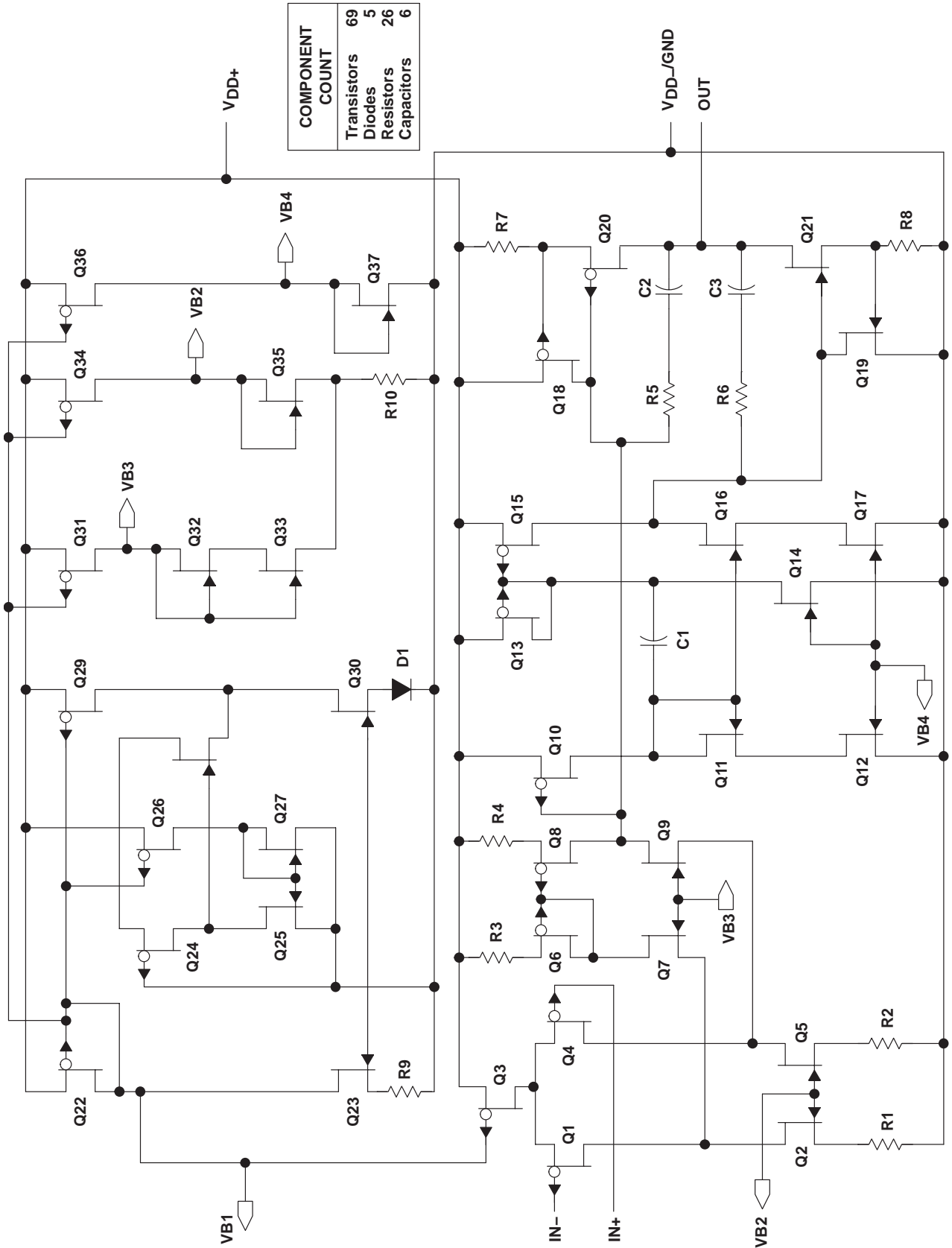
‡ Product Preview.



TLV2432-Q1, TLV2432A-Q1, TLV2434-Q1, TLV2434A-Q1  
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equivalent schematic (each amplifier)



# TLV2432-Q1, TLV2432A-Q1, TLV2434-Q1, TLV2434A-Q1

## Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT WIDE-INPUT-VOLTAGE OPERATIONAL AMPLIFIERS

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{DD}$ (see Note 1)	12 V
Differential input voltage, $V_{ID}$ (see Note 2)	$\pm V_{DD}$
Input current, $I_I$ (each input)	$\pm 5$ mA
Output current, $I_O$	$\pm 50$ mA
Total current into $V_{DD+}$	$\pm 50$ mA
Total current out of $V_{DD-}$	$\pm 50$ mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$ : Q suffix	–40°C to 125°C
Storage temperature range, $T_{stg}$	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between  $V_{DD+}$  and  $V_{DD-}$ .
  2. Differential voltages are at  $IN+$  with respect to  $IN-$ . Excessive current flows if input is brought below  $V_{DD-} - 0.3$  V.
  3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D (8)	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
D (14)	1022 mW	7.6 mW/°C	900 mW	777 mW	450 mW
PW (8)	525 mW	4.2 mW/°C	336 mW	273 mW	105 mW
PW (14)	720 mW	5.6 mW/°C	634 mW	547 mW	317 mW

### recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, $V_{DD}$	2.7	10	V
Input voltage range, $V_I$	$V_{DD-}$	$V_{DD+} - 0.8$	V
Common-mode input voltage, $V_{IC}$	$V_{DD-}$	$V_{DD+} - 0.8$	V
Operating free-air temperature, $T_A$	–40	125	°C



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electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS		$T_A$ †	TLV243x-Q1			UNIT
				MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0,$ $V_O = 0,$ $V_{DD} \pm = \pm 1.5\text{ V},$ $R_S = 50\ \Omega$	TLV243x	25°C	300	2000	$\mu\text{V}$	
			Full range	2500			
		TLV243xA	25°C	300	950		
			Full range	2000			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage	$V_{IC} = 0,$ $V_O = 0,$ $V_{DD} \pm = \pm 1.5\text{ V},$ $R_S = 50\ \Omega$		25°C to 70°C	2		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)			25°C	0.003		$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current			25°C	0.5		$\text{pA}$	
			Full range	150			
$I_{IB}$ Input bias current			25°C	1		$\text{pA}$	
	Full range	300					
$V_{ICR}$ Common-mode input voltage range	$ V_{IO}  \leq 5\text{ mV},$ $R_S = 50\ \Omega$		25°C	0 to 2.5	-0.25 to 2.75	$\text{V}$	
			Full range	0 to 2.2			
$V_{OH}$ High-level output voltage	$I_{OH} = -100\ \mu\text{A}$ $I_{OH} = -3\text{ mA}$		25°C	2.98		$\text{V}$	
			25°C	2.5			
			Full range	2.25			
$V_{OL}$ Low-level output voltage	$V_{IC} = 1.5\text{ V},$ $I_{OL} = 100\ \mu\text{A}$		25°C	0.02		$\text{V}$	
			25°C	0.83			
	$V_{IC} = 1.5\text{ V},$ $I_{OL} = 3\text{ mA}$	Full range	1				
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V},$ $V_O = 1\text{ V to }2\text{ V}$	$R_L = 2\text{ k}\Omega^\ddagger$	25°C	1.5	2.5	$\text{V}/\text{mV}$	
			Full range	0.5			
		$R_L = 1\text{ M}\Omega^\ddagger$	25°C	750			
$r_{i(d)}$ Differential input resistance			25°C	1000		$\text{G}\Omega$	
$r_{i(c)}$ Common-mode input resistance			25°C	1000		$\text{G}\Omega$	
$c_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$		25°C	8		$\text{pF}$	
$z_o$ Closed-loop output impedance	$f = 100\text{ kHz},$ $A_V = 10$		25°C	130		$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{ MIN}},$ $V_O = 1.5\text{ V},$ $R_S = 50\ \Omega$		25°C	70	83	$\text{dB}$	
			Full range	70			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 2.7\text{ V to }8\text{ V},$ $V_{IC} = V_{DD}/2,$ No load		25°C	80	95	$\text{dB}$	
			Full range	80			
$I_{DD}$ Supply current	$V_O = 1.5\text{ V},$ No load		25°C	195	250	$\mu\text{A}$	
			Full range	260			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLV2432-Q1, TLV2432A-Q1, TLV2434-Q1, TLV2434A-Q1**  
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**WIDE-INPUT-VOLTAGE OPERATIONAL AMPLIFIERS**

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operating characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$

PARAMETER		TEST CONDITIONS		$T_A$ †	TLV243x-Q1, TLV243xA-Q1			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	$V_O = 1\text{ V to }2\text{ V},$ $C_L = 100\text{ pF}‡$	$R_L = 2\text{ k}\Omega‡,$	25°C	0.15	0.25	V/ $\mu\text{s}$	
				Full range	0.1			
$V_n$	Equivalent input noise voltage	f = 10 Hz		25°C	120		nV/ $\sqrt{\text{Hz}}$	
		f = 1 kHz		25°C	22			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	2.7		$\mu\text{V}$	
		f = 0.1 Hz to 10 Hz		25°C	4			
$I_n$	Equivalent input noise current			25°C	0.6		fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_O = 0.5\text{ V to }2.5\text{ V},$ f = 1 kHz, $R_L = 2\text{ k}\Omega‡$	$A_V = 1$	25°C	0.065%			
			$A_V = 10$		0.5%			
Gain-bandwidth product		f = 10 kHz, $C_L = 100\text{ pF}‡$	$R_L = 2\text{ k}\Omega‡,$	25°C	0.5		MHz	
$B_{OM}$	Maximum output-swing bandwidth	$V_{O(PP)} = 1\text{ V},$ $R_L = 2\text{ k}\Omega‡,$	$A_V = 1,$ $C_L = 100\text{ pF}‡$	25°C	220		kHz	
$t_s$	Settling time	$A_V = -1,$ Step = 0.5 V to 2.5 V, $R_L = 2\text{ k}\Omega‡,$ $C_L = 100\text{ pF}‡$	To 0.1%	25°C	6.4		$\mu\text{s}$	
			To 0.01%		14.1			
$\phi_m$	Phase margin at unity gain	$R_L = 2\text{ k}\Omega‡,$ $C_L = 100\text{ pF}‡$		25°C	62°			
Gain margin				25°C	11		dB	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

‡ Referenced to 2.5 V

**TLV2432-Q1, TLV2432A-Q1, TLV2434-Q1, TLV2434A-Q1**  
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**WIDE-INPUT-VOLTAGE OPERATIONAL AMPLIFIERS**

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electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS		$T_A$ †	TLV243x-Q1			UNIT
				MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0,$ $V_O = 0,$ $V_{DD} \pm = \pm 2.5\text{ V},$ $R_S = 50\ \Omega$	TLV243x	25°C	300	2000	$\mu\text{V}$	
			Full range	2500			
		TLV243xA	25°C	300	950		
			Full range	2000			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage	$V_{IC} = 0,$ $V_O = 0,$ $V_{DD} \pm = \pm 2.5\text{ V},$ $R_S = 50\ \Omega$		25°C to 70°C	2		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)			25°C	0.003		$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current			25°C	0.5		$\text{pA}$	
			Full range	150			
$I_{IB}$ Input bias current			25°C	1		$\text{pA}$	
	Full range	300					
$V_{ICR}$ Common-mode input voltage range	$ V_{IO}  \leq 5\text{ mV},$ $R_S = 50\ \Omega$		25°C	0 to 4.5	-0.25 to 4.75	$\text{V}$	
			Full range	0 to 4.2			
$V_{OH}$ High-level output voltage	$I_{OH} = -100\ \mu\text{A}$ $I_{OH} = -5\text{ mA}$		25°C	4.97		$\text{V}$	
			25°C	4	4.35		
			Full range	4			
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V},$ $I_{OL} = 100\ \mu\text{A}$		25°C	0.01		$\text{V}$	
			25°C	0.8			
	$V_{IC} = 2.5\text{ V},$ $I_{OL} = 5\text{ mA}$	Full range	1.25				
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V},$ $V_O = 1\text{ V to }4\text{ V}$	$R_L = 2\text{ k}\Omega^\ddagger$	25°C	2.5	3.8	$\text{V}/\text{mV}$	
			Full range	0.5			
		$R_L = 1\text{ M}\Omega^\ddagger$	25°C	950			
$r_{i(d)}$ Differential input resistance			25°C	1000		$\text{G}\Omega$	
$r_{i(c)}$ Common-mode input resistance			25°C	1000		$\text{G}\Omega$	
$c_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$		25°C	8		$\text{pF}$	
$z_o$ Closed-loop output impedance	$f = 100\text{ kHz},$ $A_V = 10$		25°C	130		$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{ MIN}},$ $V_O = 2.5\text{ V},$ $R_S = 50\ \Omega$		25°C	70	90	$\text{dB}$	
			Full range	70			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }8\text{ V},$ $V_{IC} = V_{DD}/2,$ No load		25°C	80	95	$\text{dB}$	
			Full range	80			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V},$ No load		25°C	200	250	$\mu\text{A}$	
			Full range	270			

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$

PARAMETER		TEST CONDITIONS		$T_A$ †	TLV243x-Q1, TLV243xA-Q1			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	$V_O = 1.5\text{ V to }3.5\text{ V},$ $R_L = 2\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡		25°C	0.15	0.25	V/ $\mu\text{s}$	
				Full range	0.1			
$V_n$	Equivalent input noise voltage			25°C	100		nV/ $\sqrt{\text{Hz}}$	
				25°C	18			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage			25°C	1.9		$\mu\text{V}$	
				25°C	2.8			
$I_n$	Equivalent input noise current			25°C	0.6		fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_O = 1.5\text{ V to }3.5\text{ V},$ $f = 1\text{ kHz},$ $R_L = 2\text{ k}\Omega$ ‡		25°C	$A_V = 1$			
					$A_V = 10$			
	Gain-bandwidth product	$f = 10\text{ kHz},$ $C_L = 100\text{ pF}$ ‡	$R_L = 2\text{ k}\Omega$ ‡	25°C	0.55		MHz	
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V},$ $R_L = 2\text{ k}\Omega$ ‡	$A_V = 1,$ $C_L = 100\text{ pF}$ ‡	25°C	100		kHz	
$t_s$	Settling time	$A_V = -1,$ Step = 1.5 V to 3.5 V, $R_L = 2\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡		25°C	To 0.1%		$\mu\text{s}$	
					To 0.01%			
$\phi_m$	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$ ‡	$C_L = 100\text{ pF}$ ‡	25°C	66°			
	Gain margin			25°C	11		dB	

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q level part.

‡ Referenced to 2.5 V

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**TYPICAL CHARACTERISTICS**

**Table of Graphs**

			<b>FIGURE</b>
$V_{IO}$	Input offset voltage	Distribution vs Common-mode input voltage	2,3 4,5
$\alpha_{VIO}$	Temperature coefficient	Distribution	6,7
$I_{IB}/I_{IO}$	Input bias and input offset currents	vs Free-air temperature	8
$V_{OH}$	High-level output voltage	vs High-level output current	9,11
$V_{OL}$	Low-level output voltage	vs Low-level output current	10,12
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	13
$I_{OS}$	Short-circuit output current	vs Supply voltage	14
		vs Free-air temperature	15
$V_{ID}$	Differential input voltage	vs Output voltage	16,17
		Differential gain	vs Load resistance
$A_{VD}$	Large-signal differential voltage amplification	vs Frequency	19,20
$A_{VD}$	Differential voltage amplification	vs Free-air temperature	21,22
$z_o$	Output impedance	vs Frequency	23,24
CMRR	Common-mode rejection ratio	vs Frequency	25
		vs Free-air temperature	26
$k_{SVR}$	Supply-voltage rejection ratio	vs Frequency	27,28
		vs Free-air temperature	29
$I_{DD}$	Supply current	vs Supply voltage	30
		SR	Slew rate
$V_O$	Inverting large-signal pulse response		33,34
$V_O$	Voltage-follower large-signal pulse response		35,36
$V_O$	Inverting small-signal pulse response		37,38
$V_O$	Voltage-follower small-signal pulse response		39,40
$V_n$	Equivalent input noise voltage	vs Frequency	41, 42
		Noise voltage (referred to input)	Over a 10-second period
THD + N	Total harmonic distortion plus noise	vs Frequency	44,45
		Gain-bandwidth product	vs Free-air temperature vs Supply voltage
$\phi_m$	Phase margin	vs Frequency	19,20
		vs Load capacitance	48
	Gain margin	vs Load capacitance	49
$B_1$	Unity-gain bandwidth	vs Load capacitance	50



TYPICAL CHARACTERISTICS

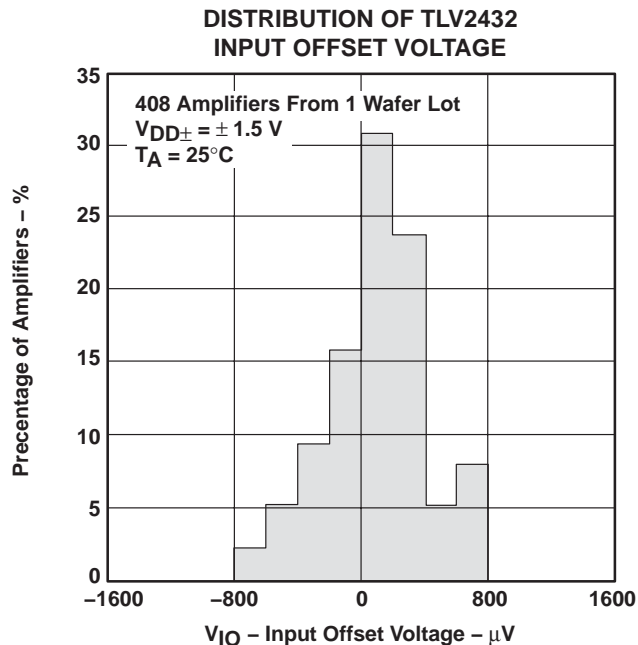


Figure 2

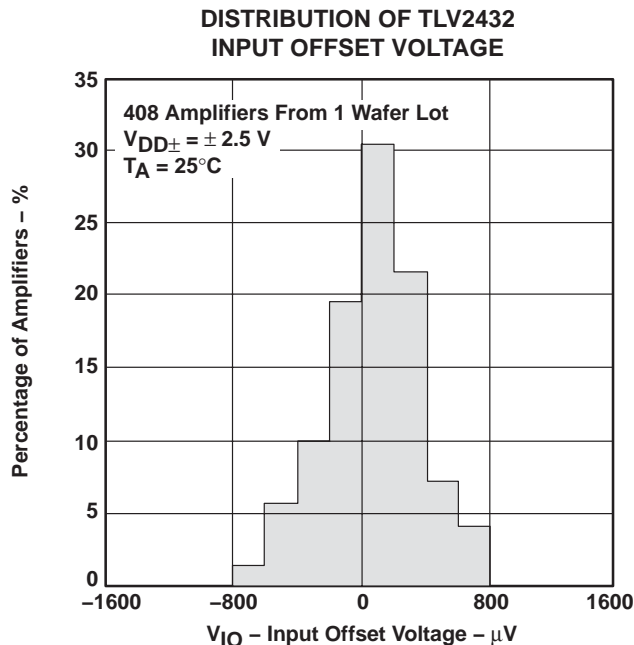


Figure 3

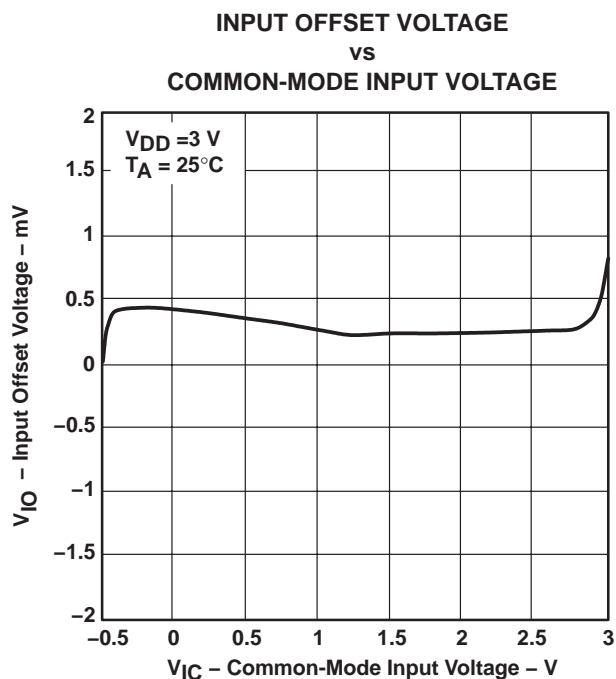


Figure 4

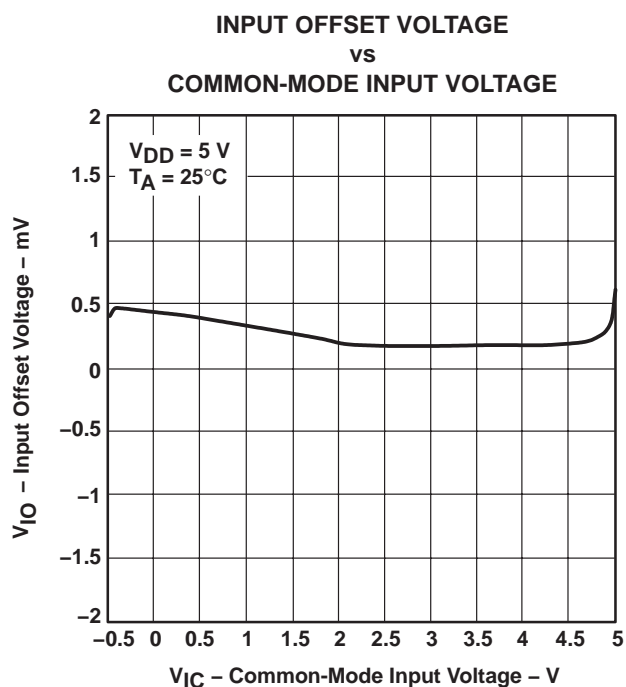
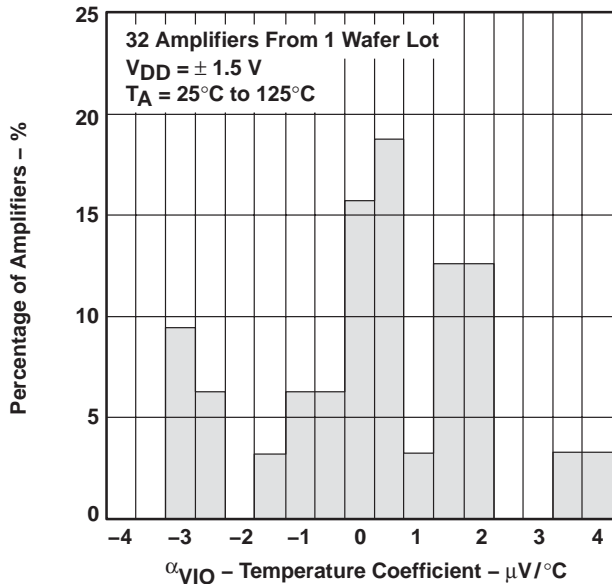


Figure 5

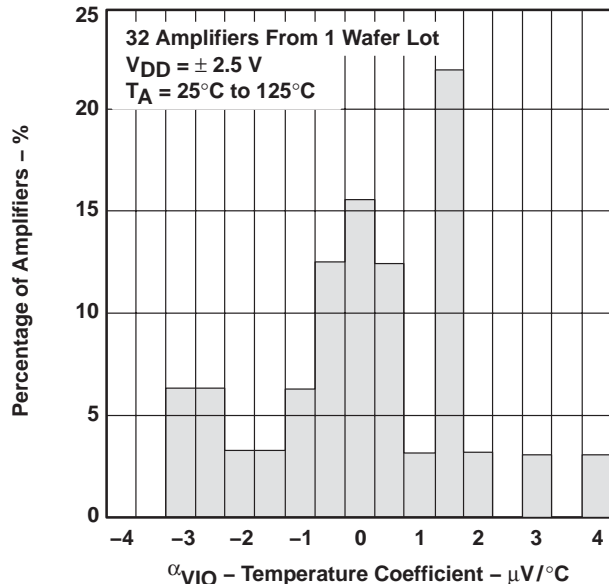
**TYPICAL CHARACTERISTICS**

**DISTRIBUTION OF TLV2432 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT**



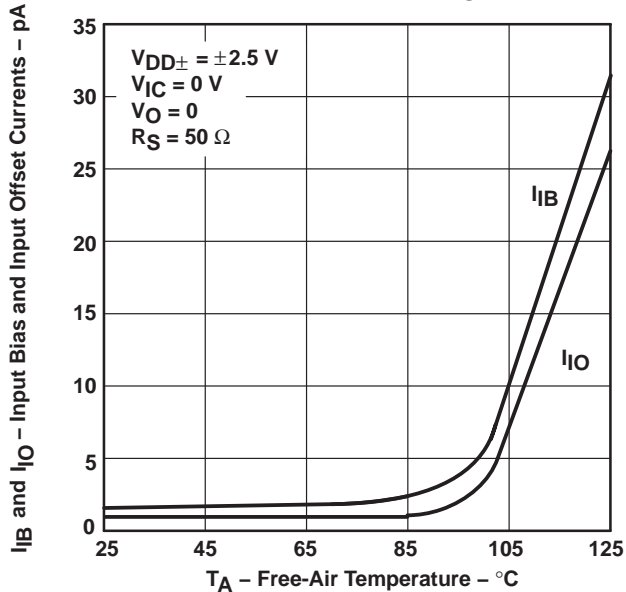
**Figure 6**

**DISTRIBUTION OF TLV2432 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT**



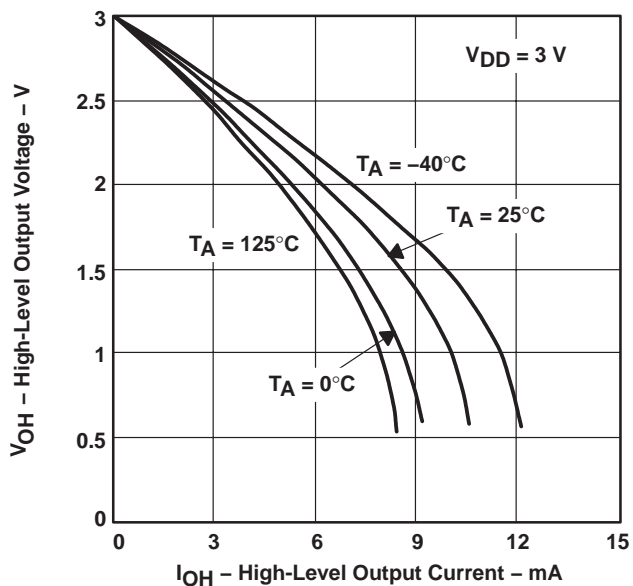
**Figure 7**

**INPUT BIAS AND INPUT OFFSET CURRENTS vs FREE-AIR TEMPERATURE**



**Figure 8**

**HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT**



**Figure 9**

TYPICAL CHARACTERISTICS

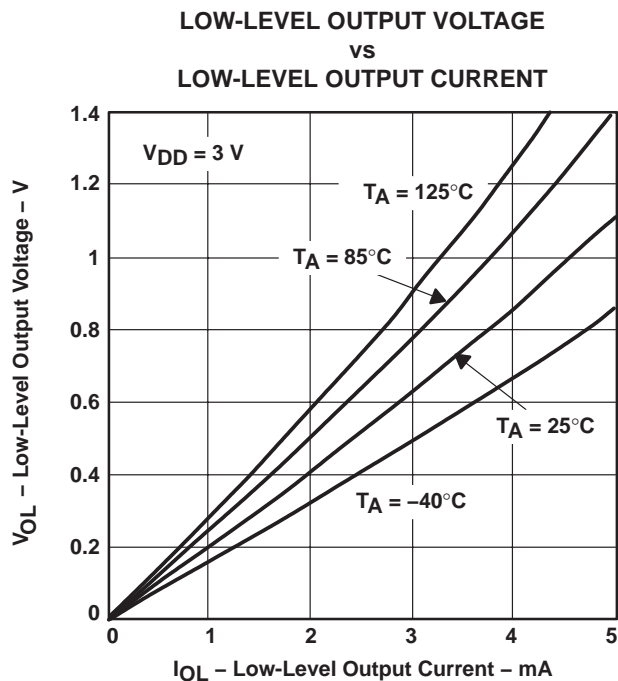


Figure 10

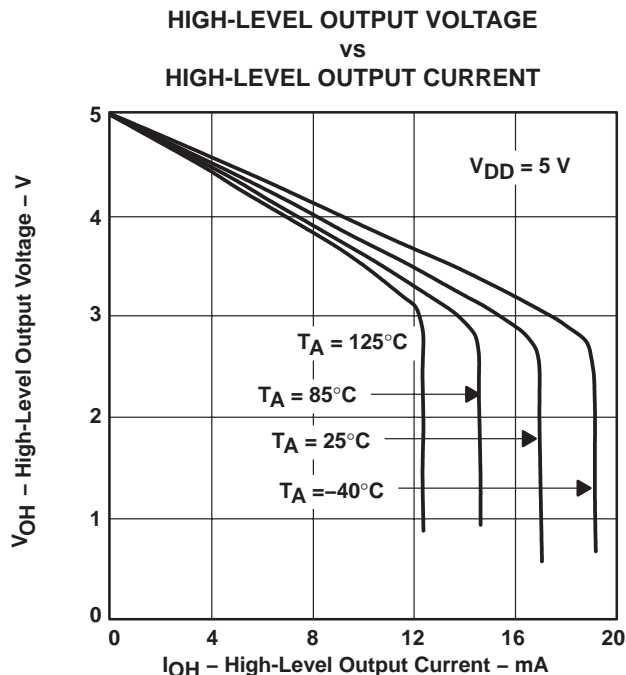


Figure 11

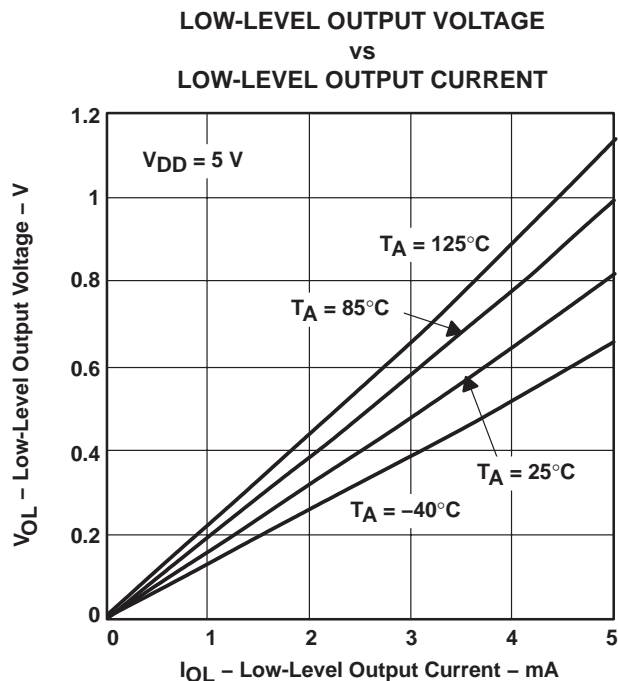


Figure 12

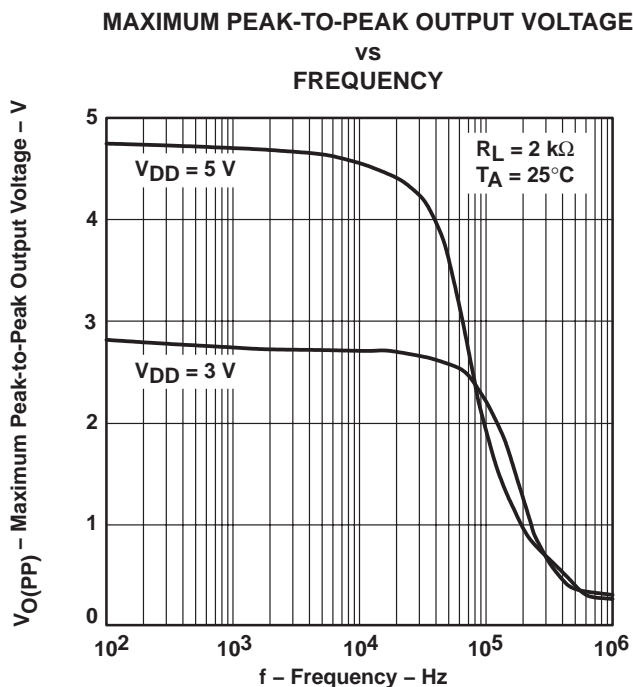


Figure 13

TYPICAL CHARACTERISTICS

SHORT-CIRCUIT OUTPUT CURRENT  
 vs  
 SUPPLY VOLTAGE

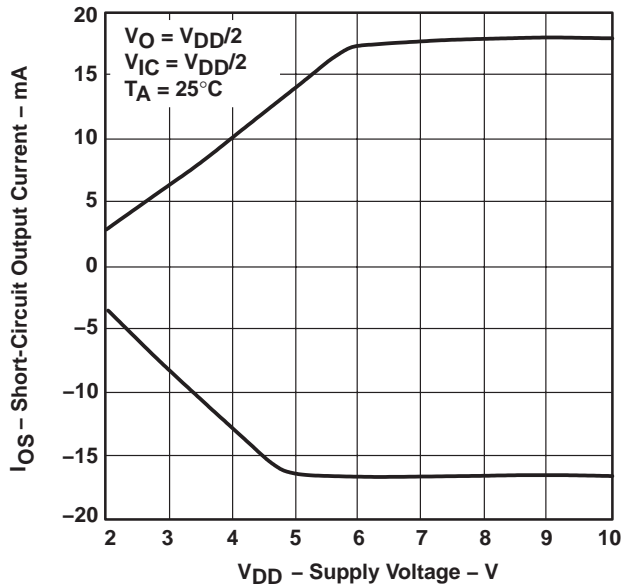


Figure 14

SHORT-CIRCUIT OUTPUT CURRENT  
 vs  
 FREE-AIR TEMPERATURE

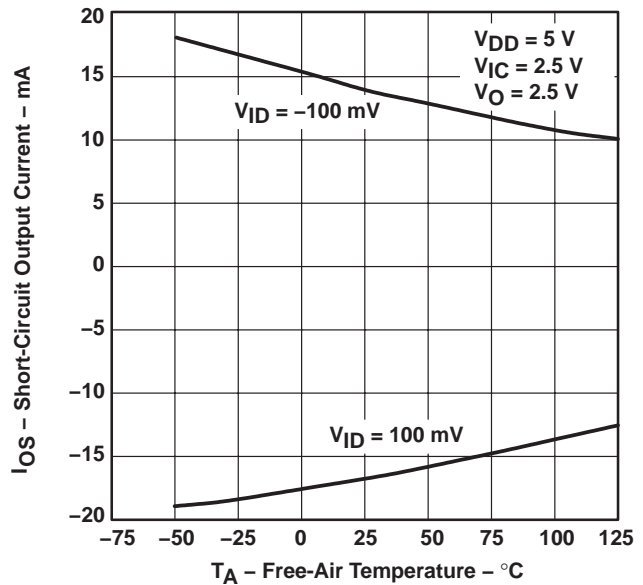


Figure 15

DIFFERENTIAL INPUT VOLTAGE  
 vs  
 OUTPUT VOLTAGE

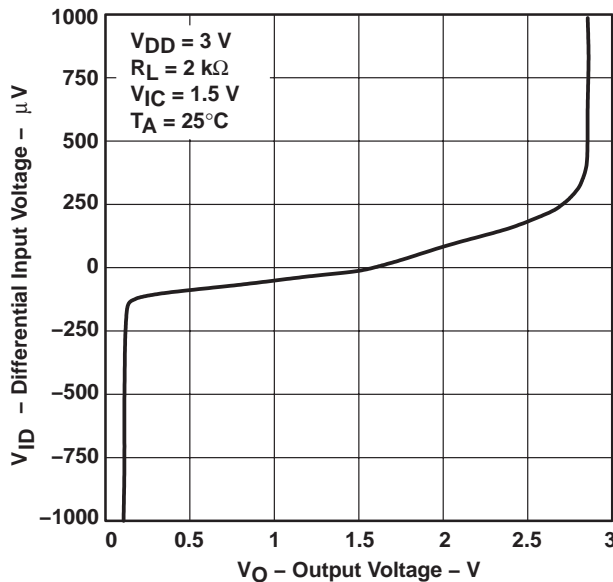


Figure 16

DIFFERENTIAL INPUT VOLTAGE  
 vs  
 OUTPUT VOLTAGE

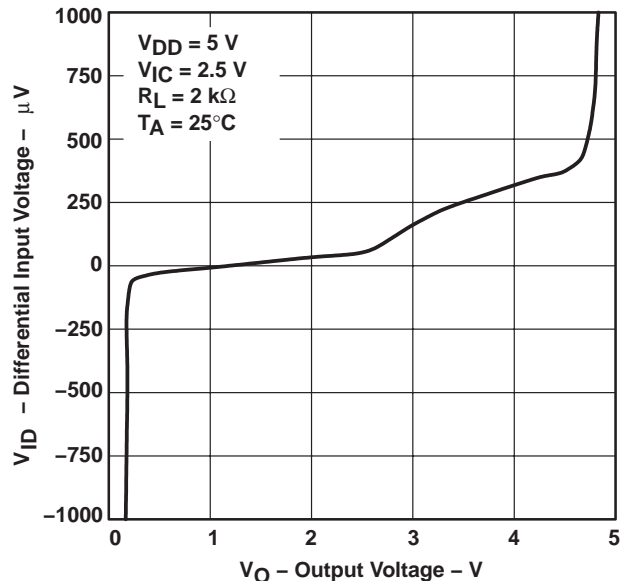


Figure 17

TYPICAL CHARACTERISTICS

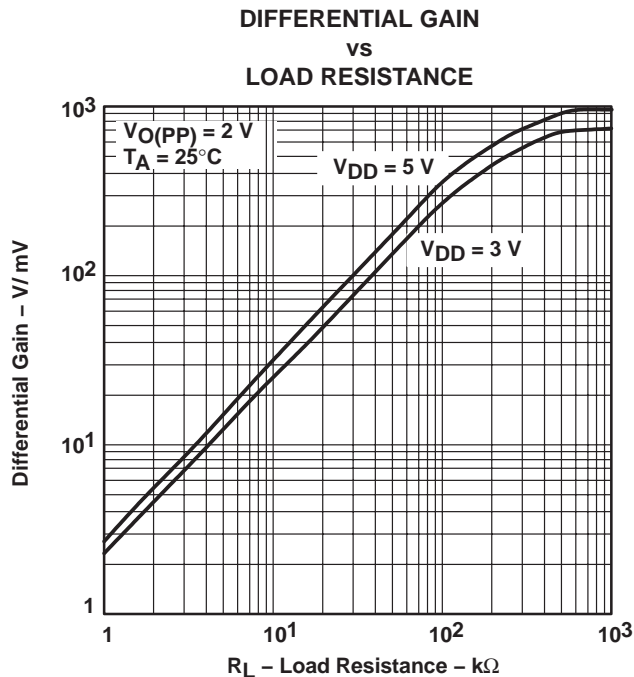


Figure 18

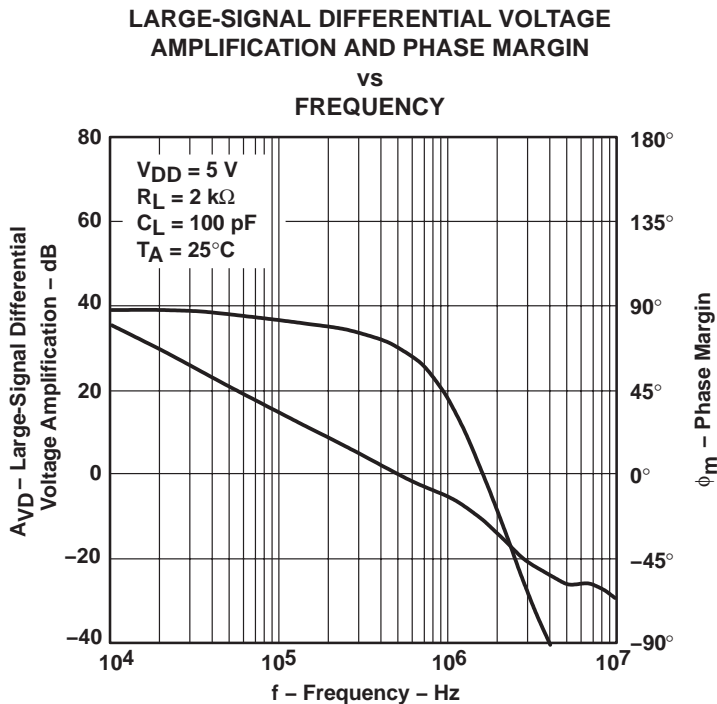


Figure 19

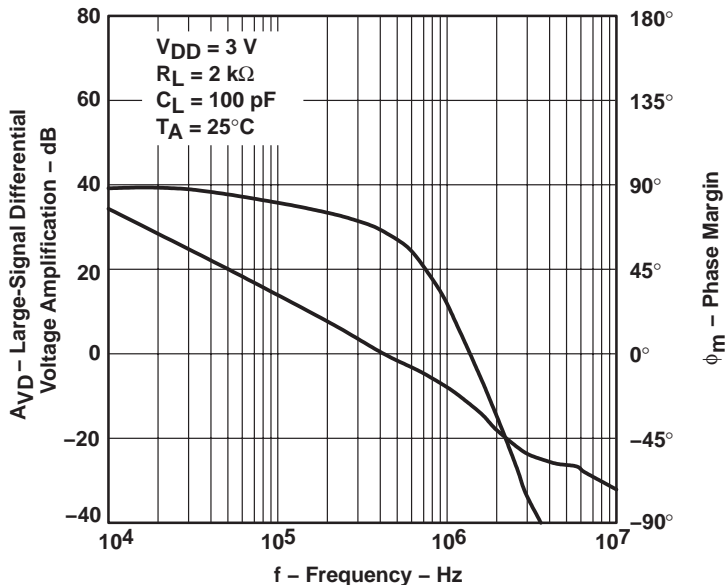
**TLV2432-Q1, TLV2432A-Q1, TLV2434-Q1, TLV2434A-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT**  
**WIDE-INPUT-VOLTAGE OPERATIONAL AMPLIFIERS**

SGLS182 – SEPTEMBER 2003

**TYPICAL CHARACTERISTICS**

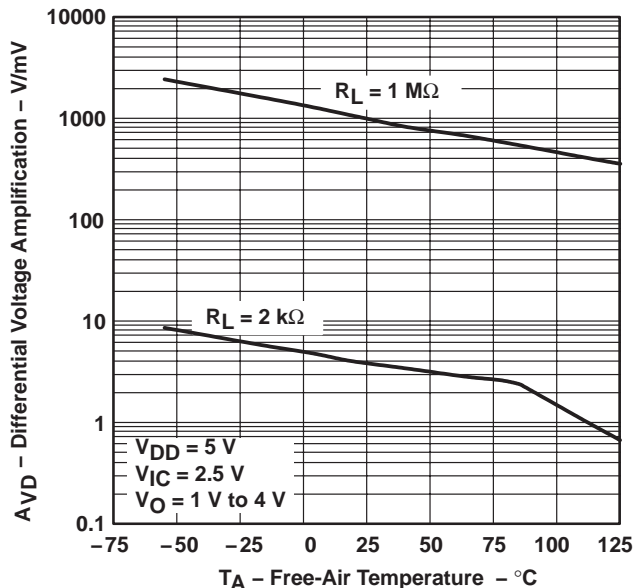
**LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN**

vs  
**FREQUENCY**



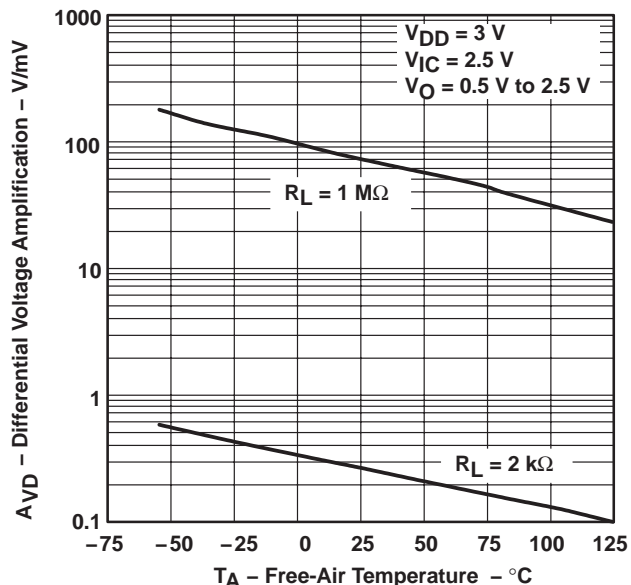
**Figure 20**

**DIFFERENTIAL VOLTAGE AMPLIFICATION**  
vs  
**FREE-AIR TEMPERATURE**



**Figure 21**

**DIFFERENTIAL VOLTAGE AMPLIFICATION**  
vs  
**FREE-AIR TEMPERATURE**



**Figure 22**



TYPICAL CHARACTERISTICS

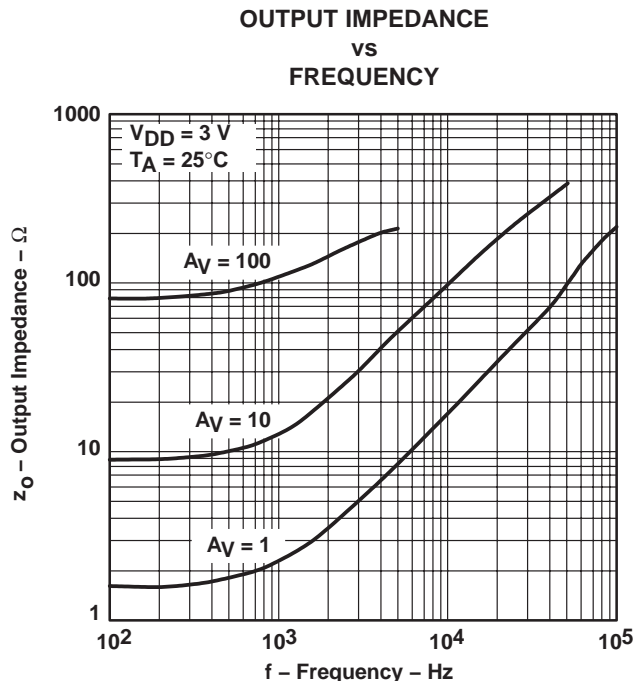


Figure 23

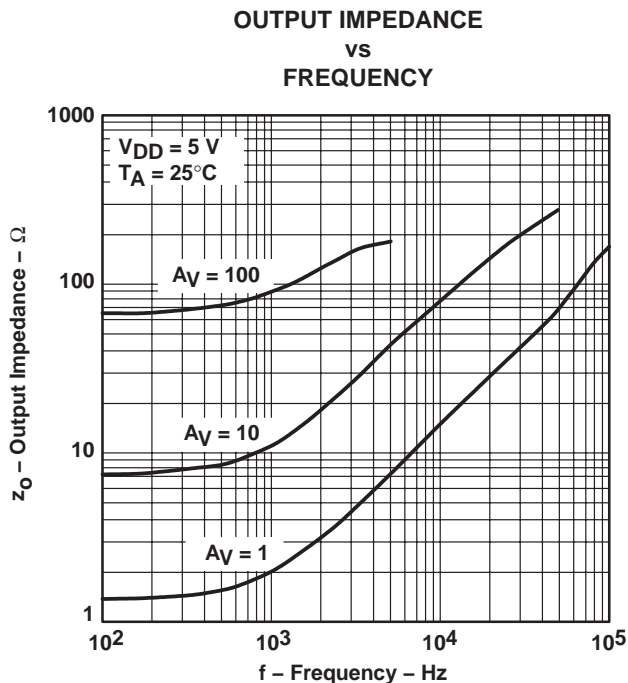


Figure 24

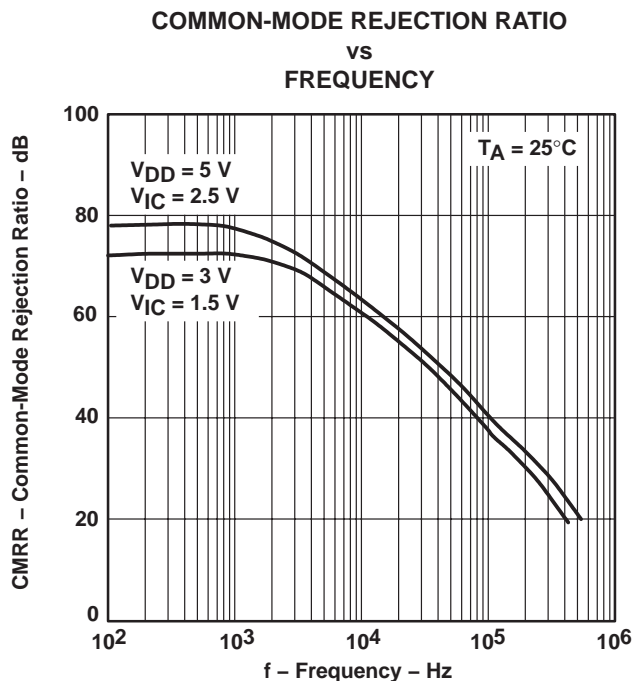


Figure 25

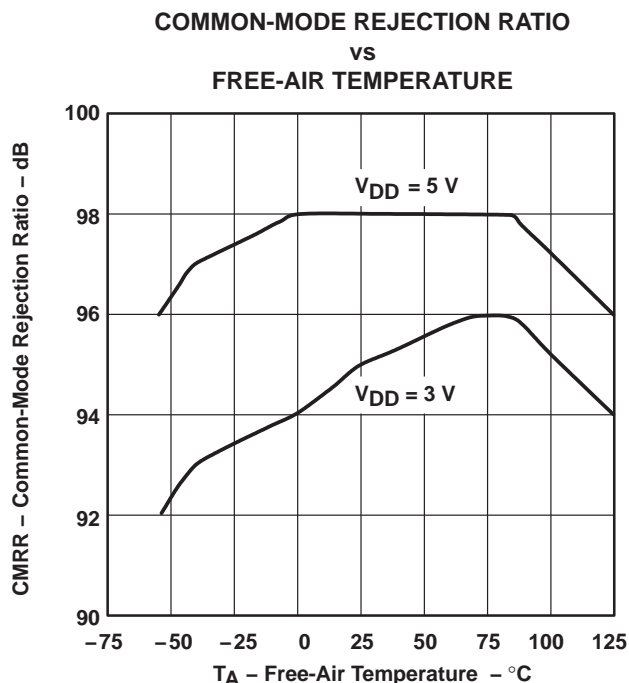
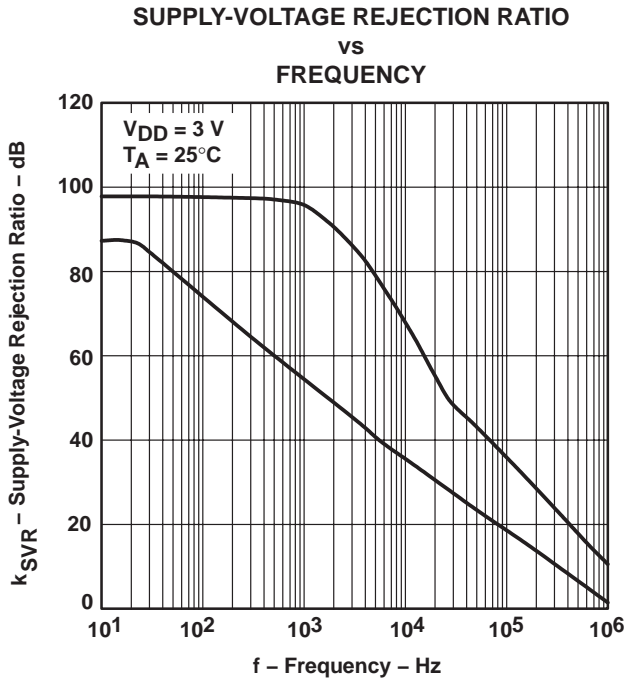
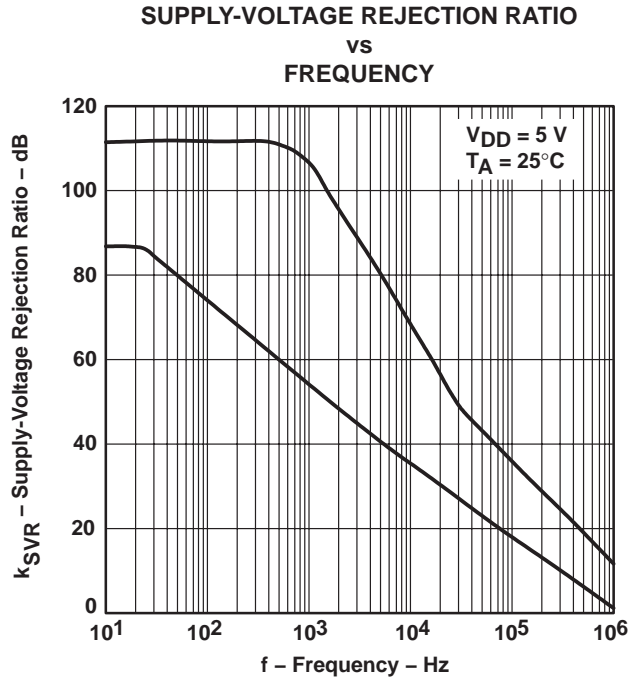


Figure 26

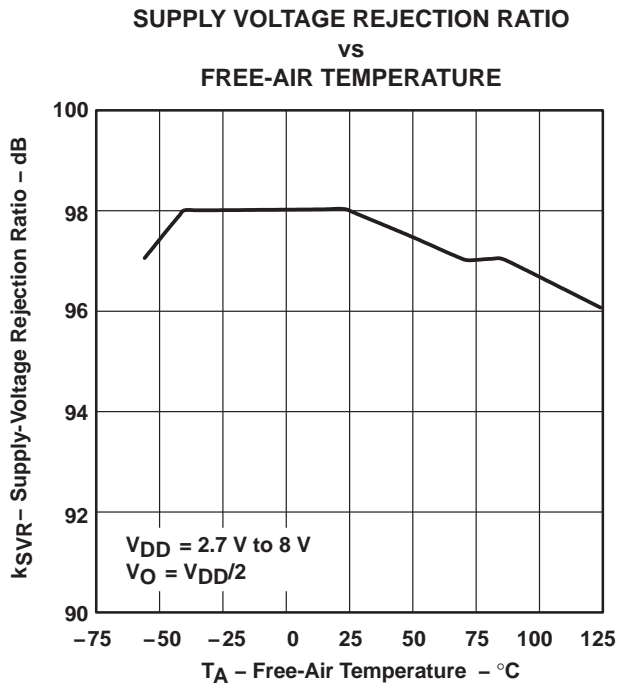
**TYPICAL CHARACTERISTICS**



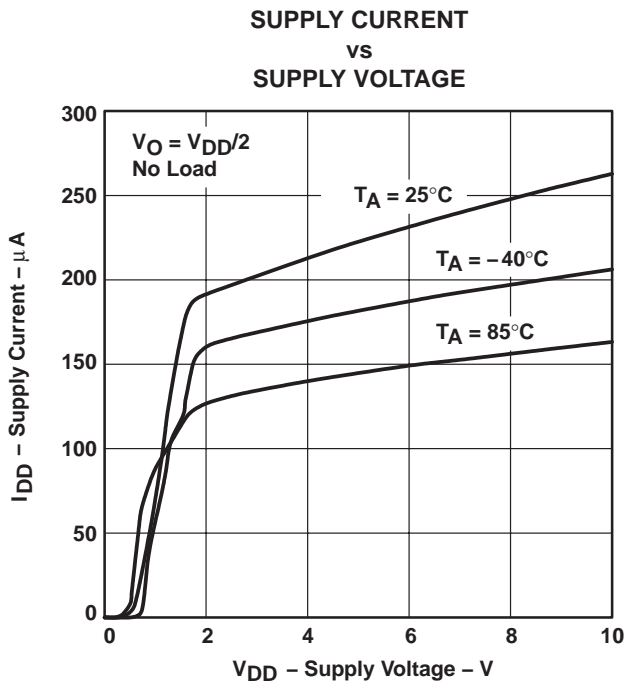
**Figure 27**



**Figure 28**



**Figure 29**



**Figure 30**

TYPICAL CHARACTERISTICS

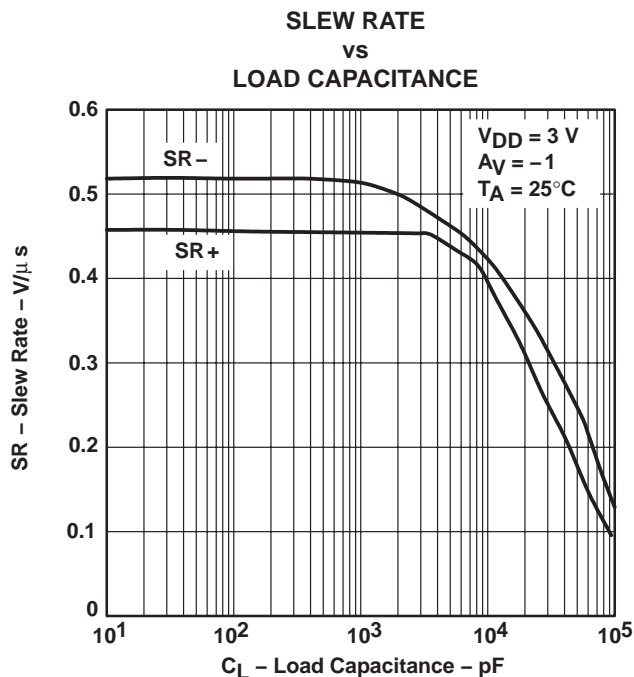


Figure 31

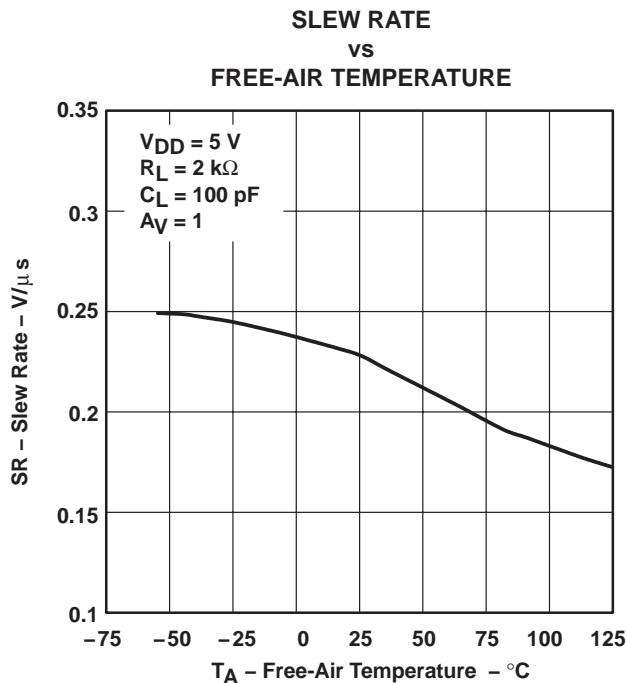


Figure 32

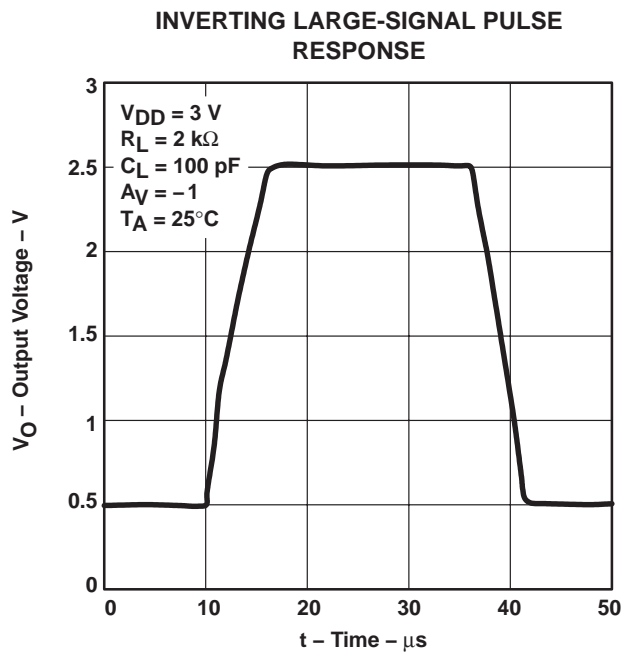


Figure 33

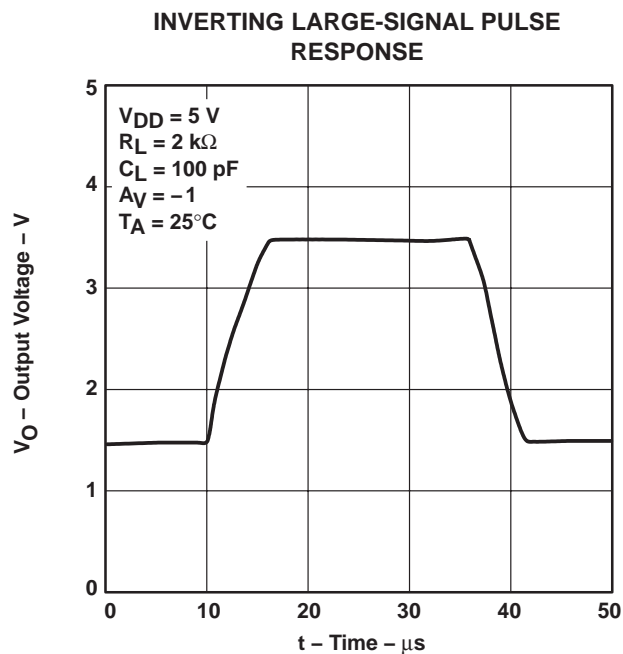
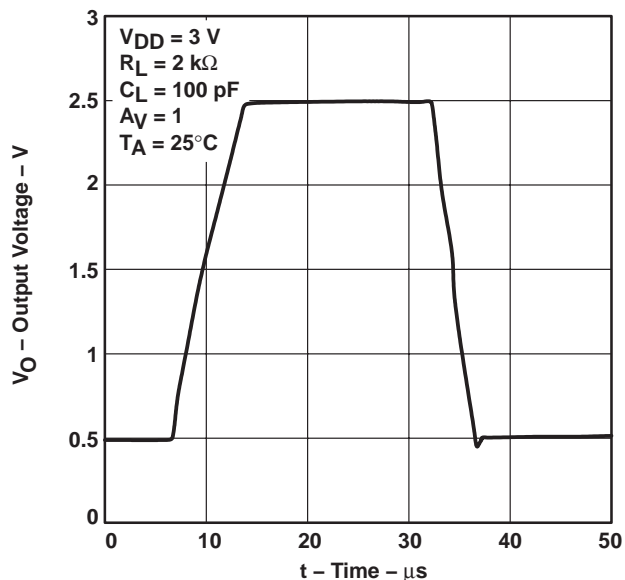


Figure 34

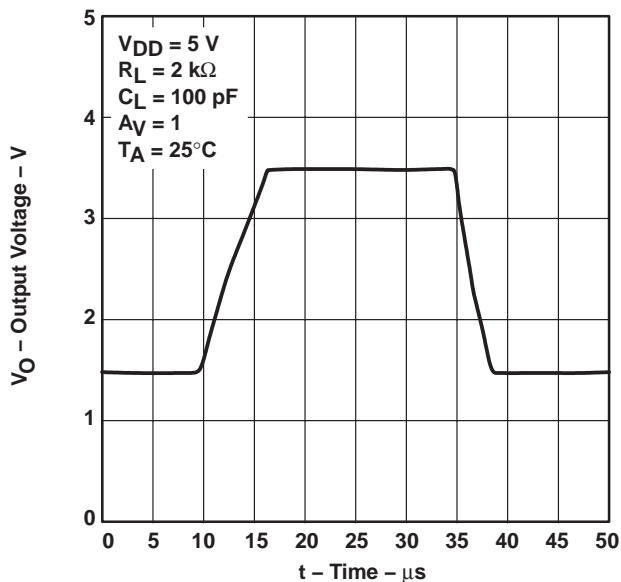
**TYPICAL CHARACTERISTICS**

**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE**



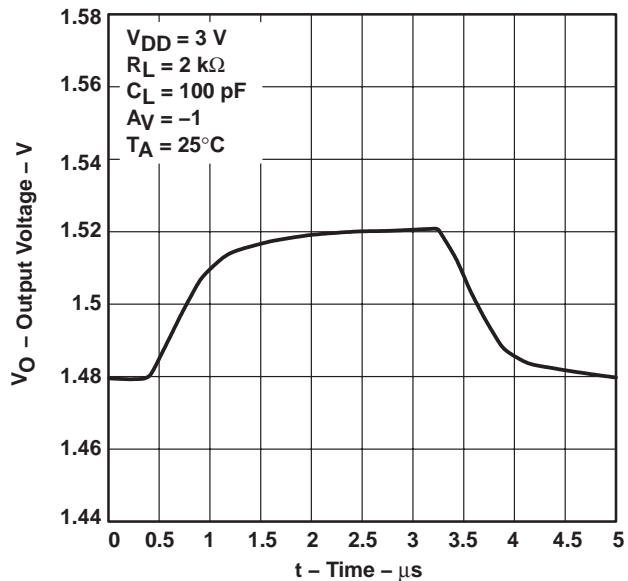
**Figure 35**

**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE**



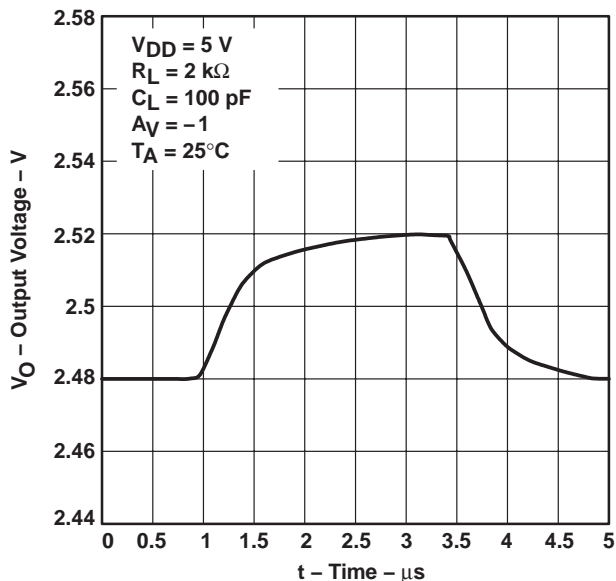
**Figure 36**

**INVERTING SMALL-SIGNAL PULSE RESPONSE**



**Figure 37**

**INVERTING SMALL-SIGNAL PULSE RESPONSE**



**Figure 38**

TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

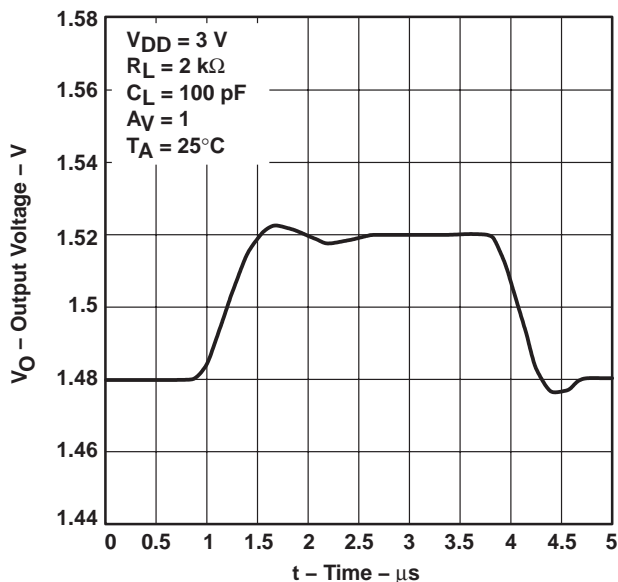


Figure 39

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

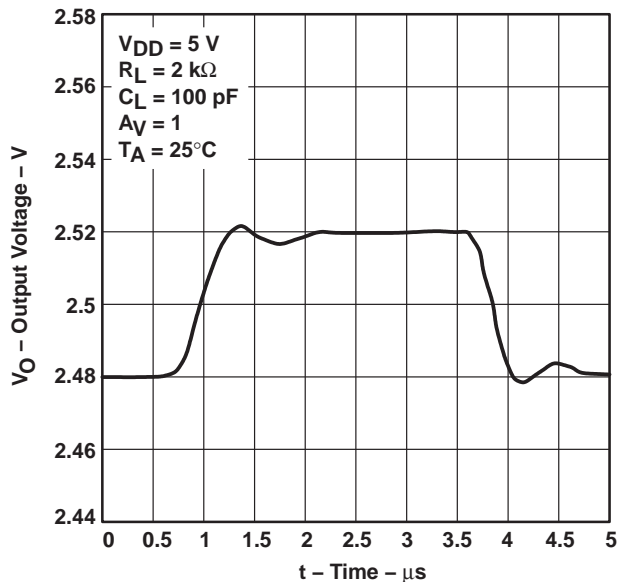


Figure 40

EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY

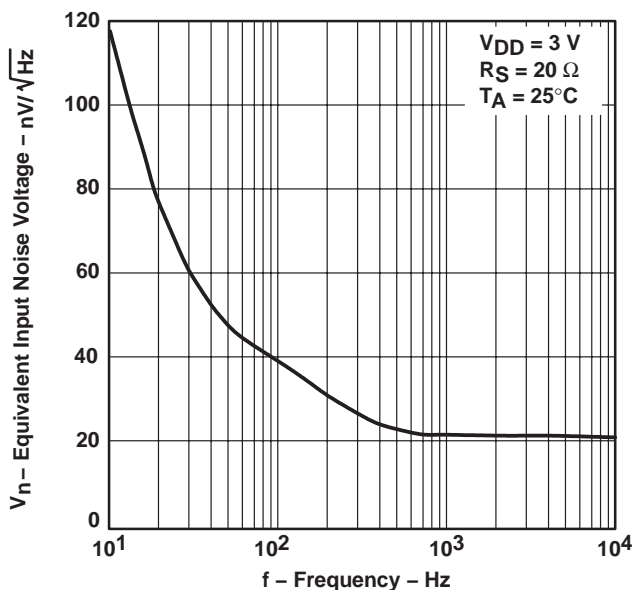


Figure 41

EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY

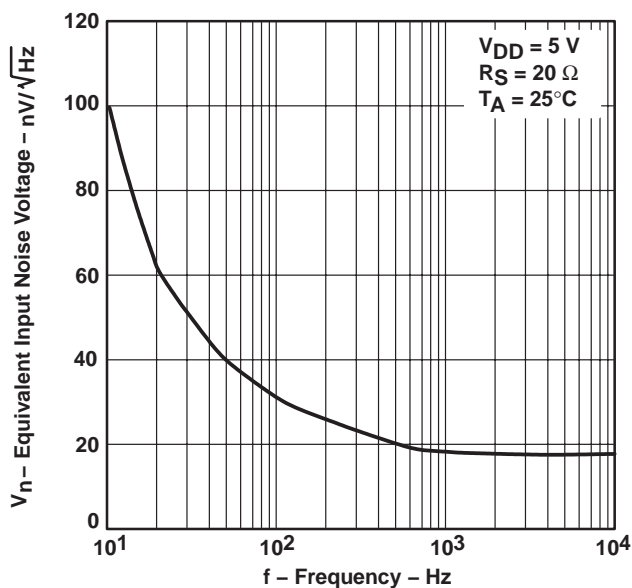
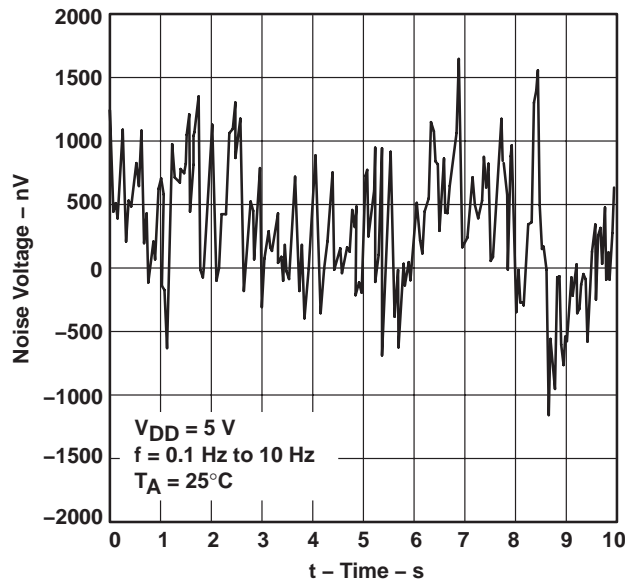


Figure 42

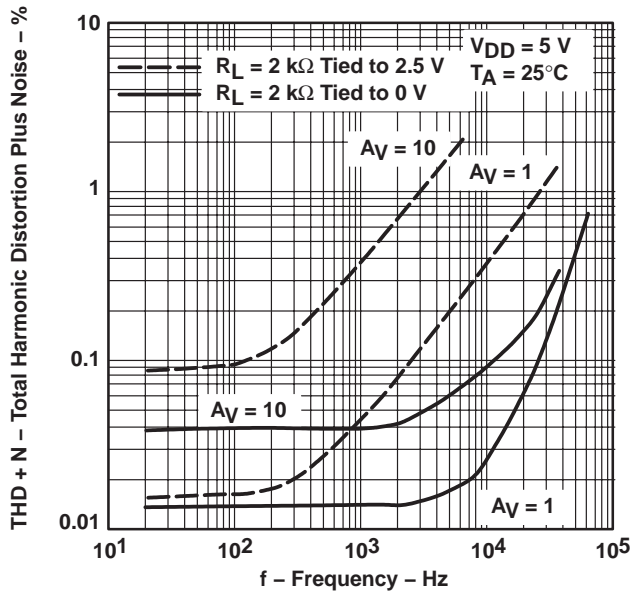
**TYPICAL CHARACTERISTICS**

**NOISE VOLTAGE OVER A 10-SECOND PERIOD**



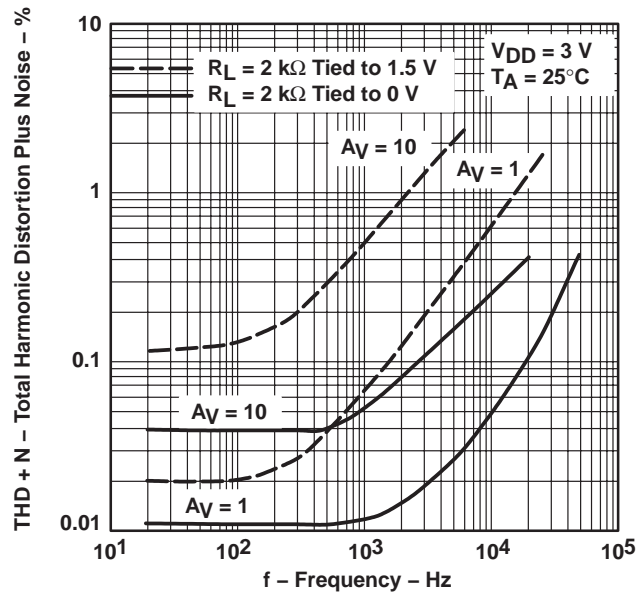
**Figure 43**

**TOTAL HARMONIC DISTORTION PLUS NOISE vs FREQUENCY**



**Figure 44**

**TOTAL HARMONIC DISTORTION PLUS NOISE vs FREQUENCY**



**Figure 45**

TYPICAL CHARACTERISTICS

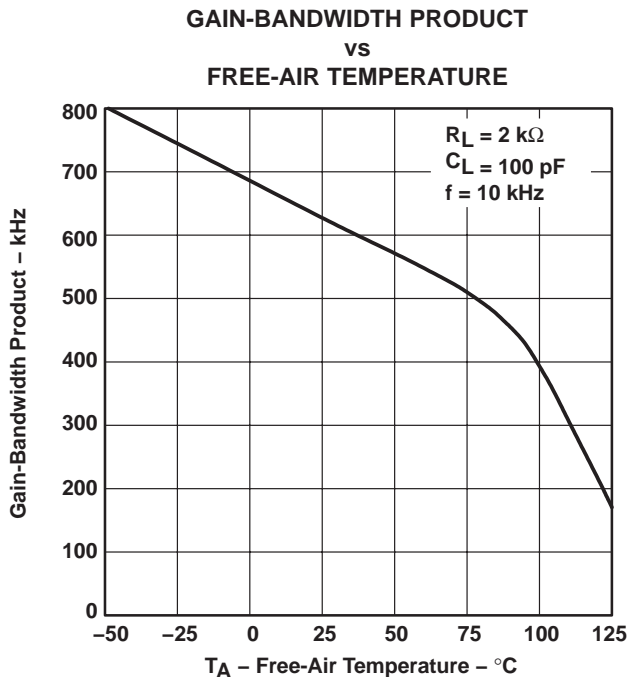


Figure 46

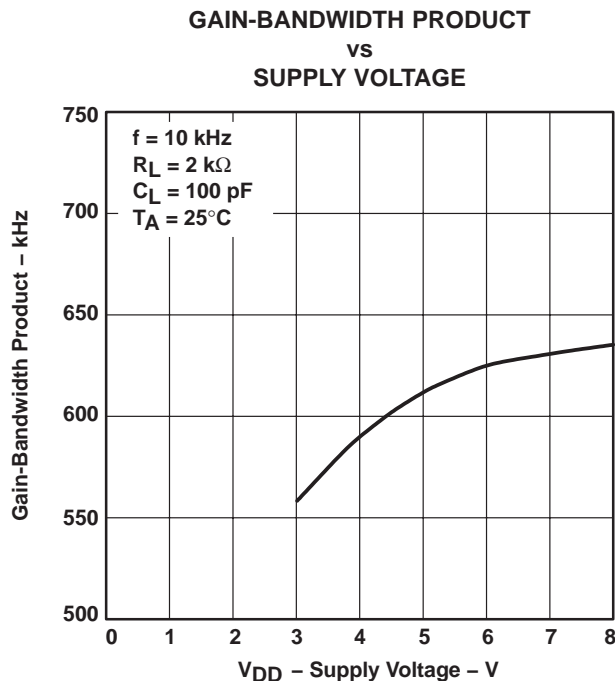


Figure 47

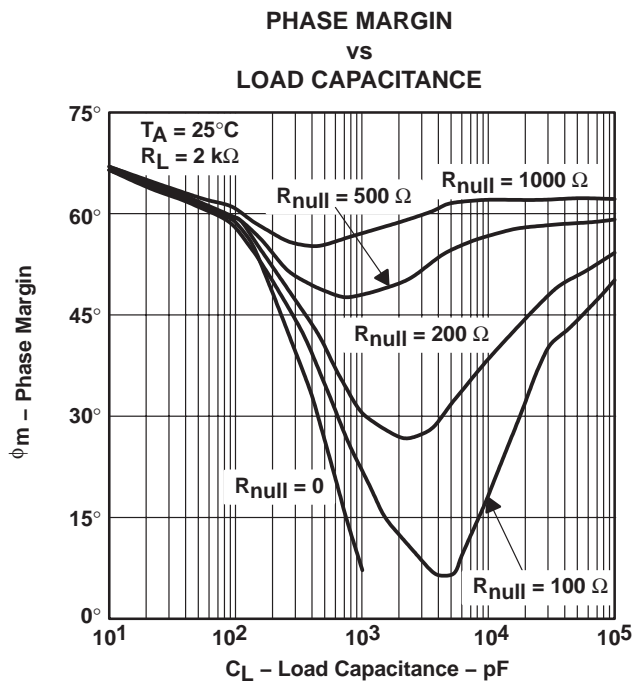


Figure 48

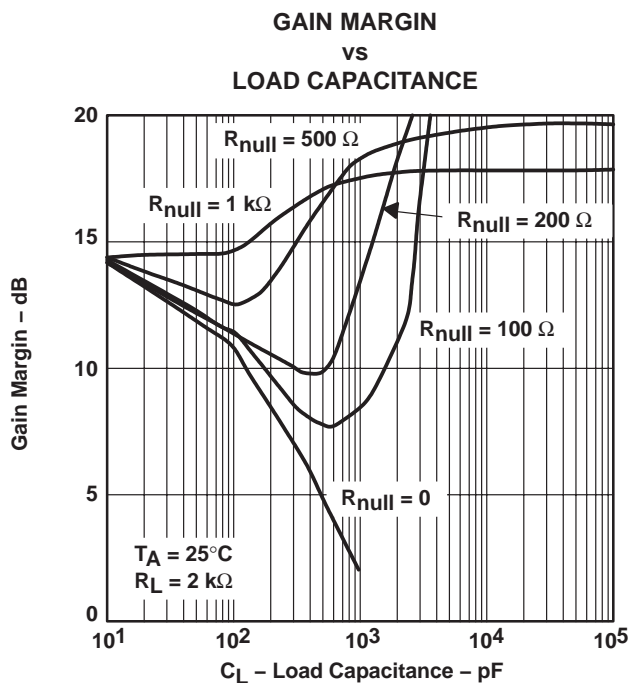


Figure 49

TYPICAL CHARACTERISTICS

UNITY-GAIN BANDWIDTH  
vs  
LOAD CAPACITANCE

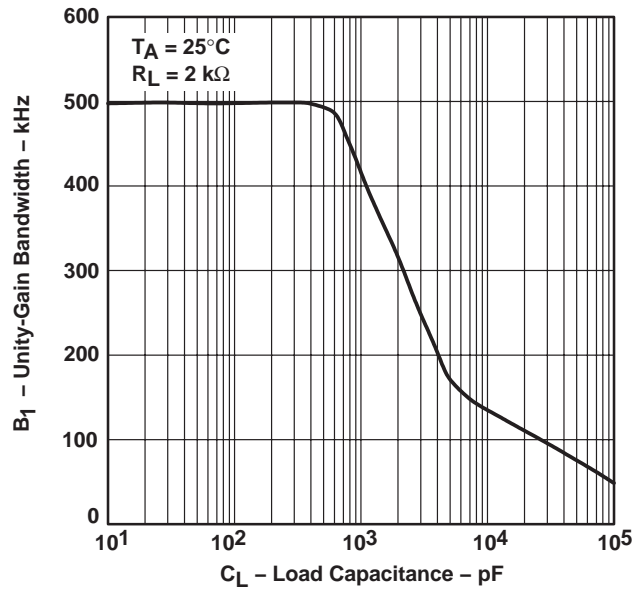


Figure 50

# TLV2432-Q1, TLV2432A-Q1, TLV2434-Q1, TLV2434A-Q1 Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT WIDE-INPUT-VOLTAGE OPERATIONAL AMPLIFIERS

SGLS182 – SEPTEMBER 2003

## APPLICATION INFORMATION

### macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 51 are generated using the TLV243x typical electrical and operating characteristics at  $T_A = 25^\circ\text{C}$ . Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 4: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

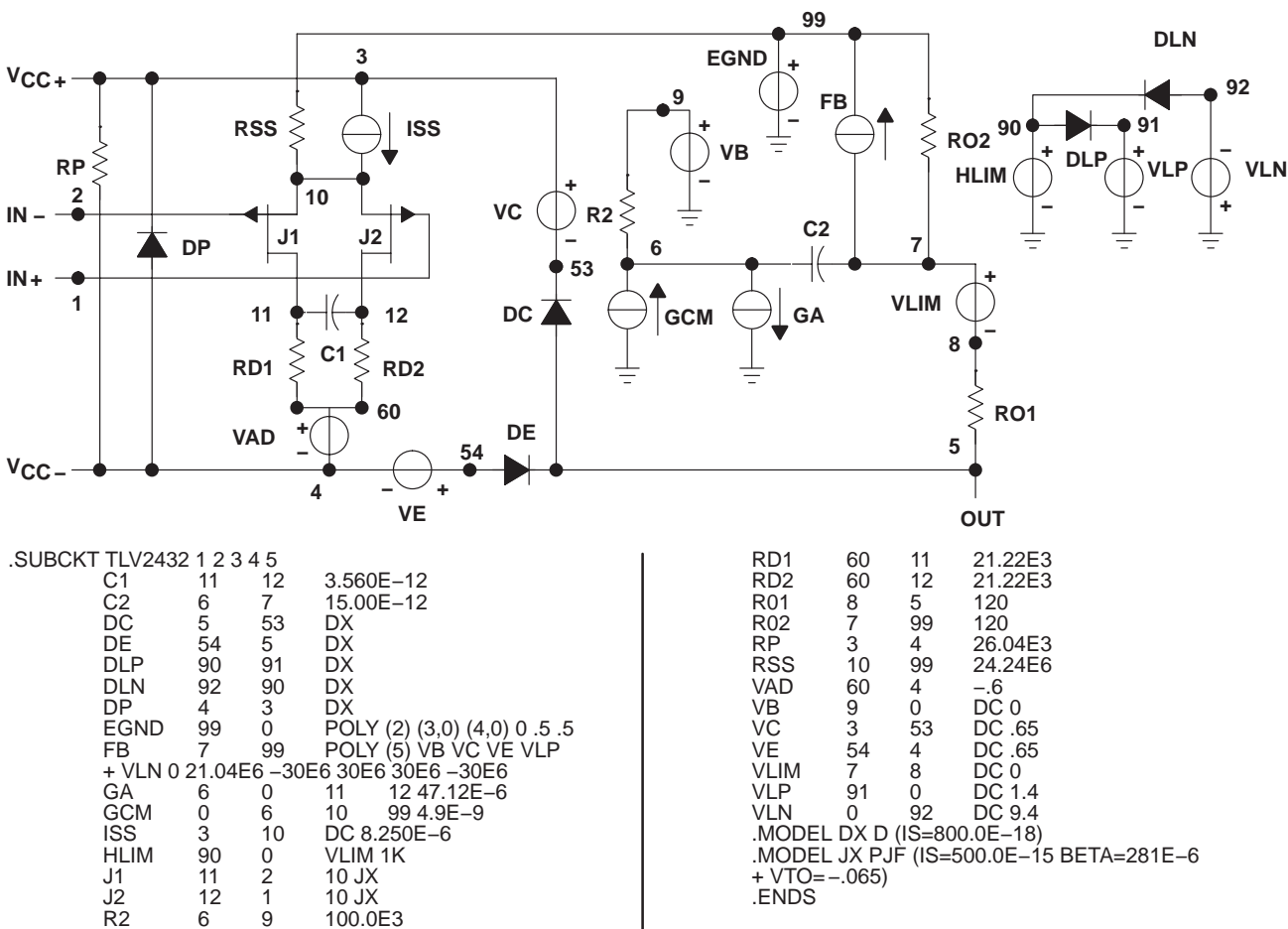


Figure 51. Boyle Macromodel and Subcircuit

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**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TLV2432AQDRQ1	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
TLV2432QDRQ1	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - May not be currently available - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**None:** Not yet available Lead (Pb-Free).

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

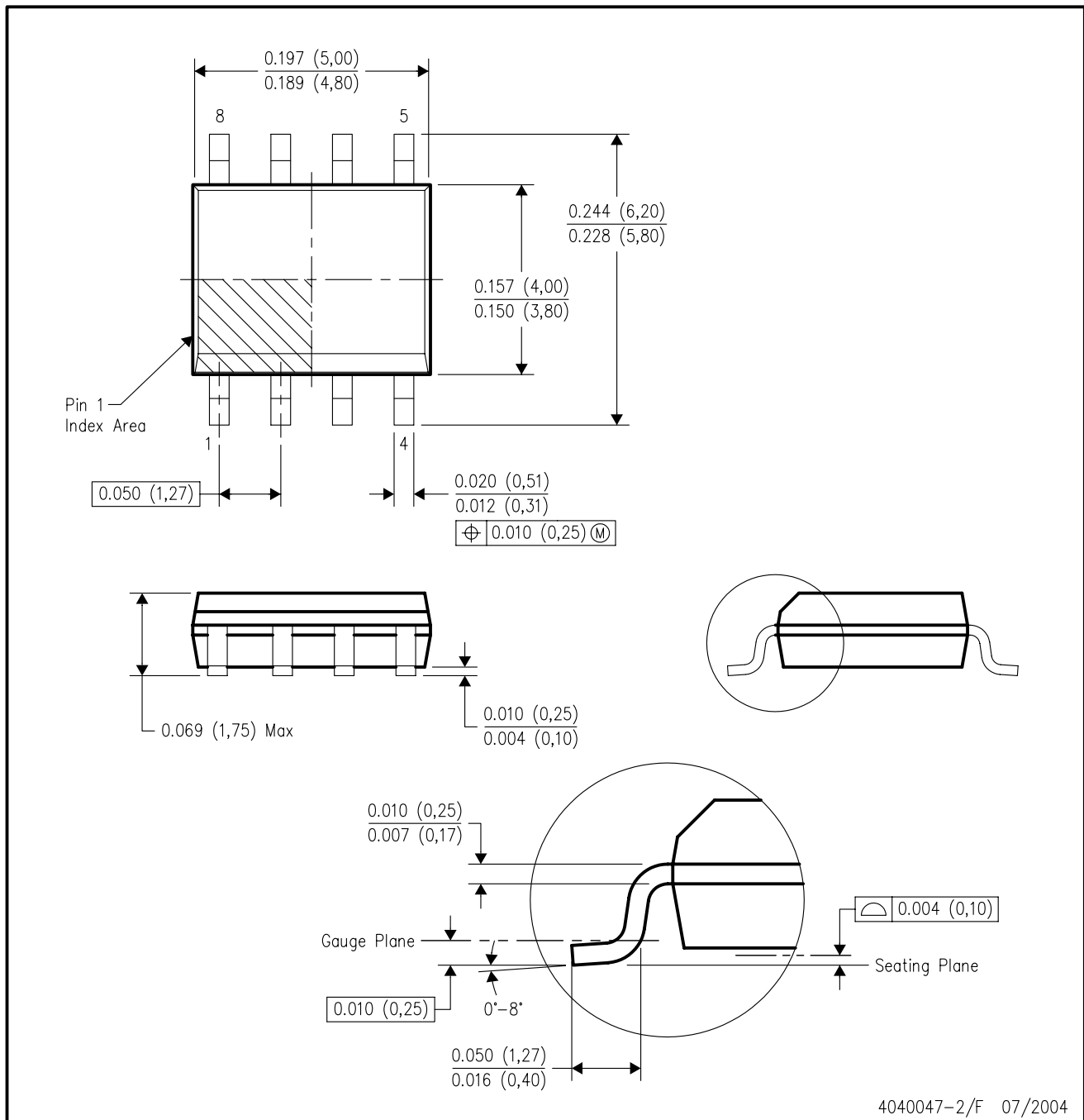
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-012 variation AA.

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Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>	Automotive	<a href="http://www.ti.com/automotive">www.ti.com/automotive</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>	Broadband	<a href="http://www.ti.com/broadband">www.ti.com/broadband</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>	Digital Control	<a href="http://www.ti.com/digitalcontrol">www.ti.com/digitalcontrol</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>	Military	<a href="http://www.ti.com/military">www.ti.com/military</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>	Optical Networking	<a href="http://www.ti.com/opticalnetwork">www.ti.com/opticalnetwork</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>	Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
		Telephony	<a href="http://www.ti.com/telephony">www.ti.com/telephony</a>
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